# Cost-Effective, 2A Sink/Source Bus Termination Regulator

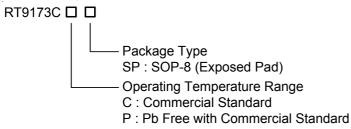
## **General Description**

The RT9173C is a simple, cost-effective and high-speed linear regulator designed to generate termination voltage in double data rate (DDR) memory system to comply with the JEDEC SSTL\_2 and SSTL\_18 or other specific interfaces such as HSTL, SCSI-2 and SCSI-3 etc. devices requirements. The regulator is capable of actively sinking or sourcing up to 2A while regulating an output voltage to within 40mV. The output termination voltage cab be tightly regulated to track  $1/2V_{DDQ}$  by two external voltage divider resistors or the desired output voltage can be pro-grammed by externally forcing the REFEN pin voltage.

The RT9173C also incorporates a high-speed differential amplifier to provide ultra-fast response in line/load transient. Other features include extremely low initial offset voltage, excellent load regulation, current limiting in bi-directions and on-chip thermal shut-down protection.

The RT9173C are available in the SOP-8 (Exposed Pad) surface mount packages.

## **Ordering Information**



#### Note:

RichTek Pb-free products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- -Suitable for use in SnPb or Pb-free soldering processes.
- -100% matte tin (Sn) plating.

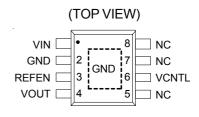
#### **Features**

- Ideal for DDR-I, DDR-II and DDR-III V<sub>TT</sub> Applications
- Sink and Source 2A Continuous Current
- Integrated Power MOSFETs
- Generates Termination Voltage for SSTL\_2,
   SSTL \_18, HSTL, SCSI-2 and SCSI-3 Interfaces
- High Accuracy Output Voltage at Full-Load
- Output Adjustment by Two External Resistors
- Low External Component Count
- Shutdown for Suspend to RAM (STR) Functionality with High-Impedance Output
- Current Limiting Protection
- On-Chip Thermal Protection
- Available in SOP-8 (Exposed Pad) Packages
- VIN and VCNTL No Power Sequence Issue
- RoHS Compliant and 100% Lead (Pb)-Free

## **Applications**

- Desktop PCs, Notebooks, and Workstations
- Graphics Card Memory Termination
- Set Top Boxes, Digital TVs, Printers
- Embedded Systems
- Active Termination Buses
- DDR-I, DDR-II and DDR-III Memory Systems

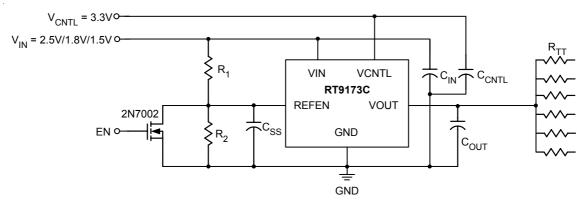
# **Pin Configurations**



SOP-8 (Exposed Pad)



# **Typical Application Circuit**



 $R_1 = R_2 = 100 k\Omega$ ,  $R_{TT} = 50 \Omega / 33 \Omega / 25 \Omega$ 

 $C_{OUT(MIN)}$  = 10 $\mu$ F (Ceramic) + 1000 $\mu$ F under the worst case testing condition

 $C_{SS} = 1\mu F$ ,  $C_{IN} = 470\mu F$  (Low ESR),  $C_{CNTL} = 47\mu F$ 

## **Functional Pin Description**

#### VIN

Input voltage which supplies current to the output pin. Connect this pin to a well-decoupled supply voltage. To prevent the input rail from dropping during large load transient, a large, low ESR capacitor is recommended to use. The capacitor should be placed as close as possible to the VIN pin.

#### **GND**

Common Ground (Exposed pad is connected to GND). The GND pad area should be as large as possible and using many vias to conduct the heat into the buried GND plate of PCB layer.

#### **VCNTL**

VCNTL supplies the internal control circuitry and provides the drive voltage. The driving capability of output current is proportioned to the VCNTL. Connect this pin to 3.3V bias supply to handle large output current with at least  $10\mu$ F capacitor from this pin to GND.

#### **REFEN**

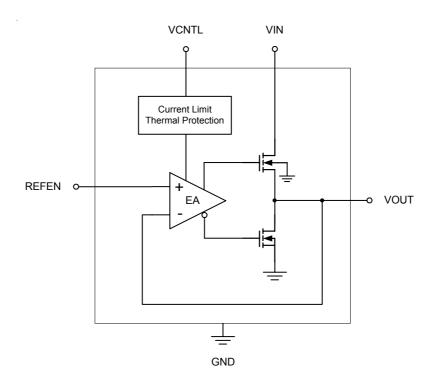
Reference voltage input and active low shutdown control pin. Two resistors dividing down the VIN voltage on the pin to create the regulated output voltage. Pulling the pin to ground turns off the device by an open-drain, such as 2N7002, signal N-Channel MOSFET.

#### **VOUT**

Regulator output. VOUT is regulated to REFEN voltage that is used to terminate the bus resistors. It is capable of sinking and sourcing current while regulating the output rail. To maintain adequate large signal transient response, typical value of  $1000\mu F$  AL electrolytic capacitor with  $10\mu F$  ceramic capacitors are recommended to reduce the effects of current transients on VOUT.



# **Function Block Diagram**



# **Test Circuit**

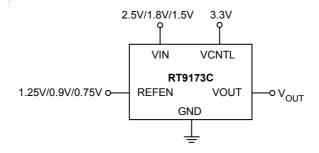


Figure 1. Test Circuit for Typical Operating Characteristics Curves



# Absolute Maximum Ratings (Note 1)

• Input Voltage, V <sub>IN</sub>	6V
Control Voltage, V <sub>CNTL</sub>	6V
<ul> <li>Power Dissipation, P<sub>D</sub> @ T<sub>A</sub> = 25°C</li> </ul>	
SOP-8 (Exposed Pad)	1.33W
Package Thermal Resistance (Note 4)	
SOP-8 (Exposed Pad), $\theta_{JA}$	75°C/W
SOP-8 (Exposed Pad), $\theta_{JC}$	
• Junction Temperature	125°C
Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	–65°C to 150°C
ESD Susceptibility (Note 2)	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	200V
Recommended Operating Conditions (Note 3)	
• Input Voltage, V <sub>IN</sub>	2.5V to 1.5V ± 3%

## **Electrical Characteristics**

 $(V_{IN} = 2.5V/1.8V/1.5V. \ V_{CNTI} = 3.3V. \ V_{REFEN} = 1.25V/0.9V/0.75V, \ C_{OUT} = 10 \mu F$  (Ceramic),  $T_A = 25^{\circ}$  C, unless otherwise specified)

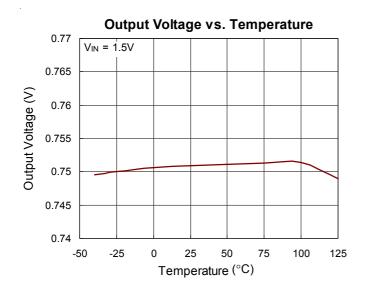
Parameter	Symbol	Test Conditions	Min	Тур	Max	Units		
Input								
V <sub>CNTL</sub> Operation Current	I <sub>CNTL</sub>	I <sub>OUT</sub> = 0A	-	1	2.5	mA		
Standby Current (Note 7)	I <sub>STBY</sub>	$V_{REFEN} < 0.2V$ (Shutdown), $R_{LOAD} = 180\Omega$		50	90	μΑ		
Output (DDR / DDR II / DDR III)								
Output Offset Voltage (Note 5)	Vos	I <sub>OUT</sub> = 0A	-20	1	+20	mV		
Load Regulation (Note 6)	$\Delta V_{LOAD}$	I <sub>OUT</sub> = +2A	-20		+20	mV		
		I <sub>OUT</sub> = -2A						
Protection								
Current limit	I <sub>LIM</sub>		2.2	-		Α		
Thermal Shutdown Temperature	T <sub>SD</sub>	$3.3V \le V_{CNTL} \le 5V$	125	170		ç		
Thermal Shutdown Hysteresis	$\Delta T_{SD}$	$3.3V \le V_{CNTL} \le 5V$		35		°C		
REFEN Shutdown								
Shutdown Threshold	V <sub>IH</sub>	Enable	0.6			V		
	$V_{IL}$	Shutdown			0.2	V		

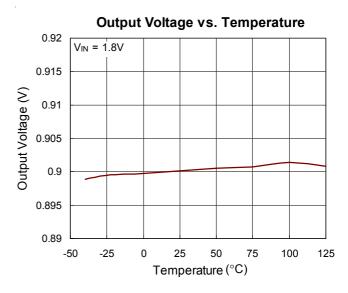


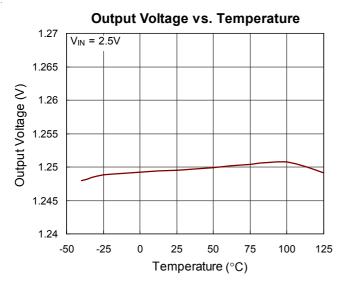
- **Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2. Devices are ESD sensitive. Handling precaution recommended.
- Note 3. The device is not guaranteed to function outside its operating conditions.
- **Note 4.**  $\theta_{JA}$  is measured in the natural convection at  $T_A$  = 25°C on a high effective thermal conductivity test board (4 Layers, 2S2P) of JEDEC 51-7 thermal measurement standard. The case point of  $\theta_{JC}$  is on the expose pad for SOP-8 (Exposed Pad) package.
- Note 5. Vos offset is the voltage measurement defined as VouT subtracted from V<sub>REFEN</sub>.
- **Note 6.** Regulation is measured at constant junction temperature by using a 5ms current pulse. Devices are tested for load regulation in the load range from 0A to 2A.
- Note 7. Standby current is the input current drawn by a regulator when the output voltage is disabled by a shutdown signal on REFEN pin ( $V_{IL} < 0.2V$ ). It is measured with  $V_{IN} = V_{CNTL} = 5V$ .

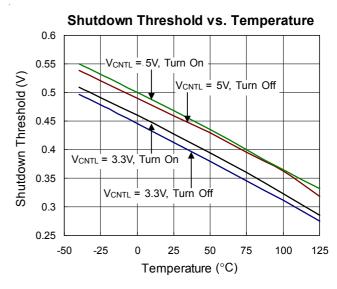


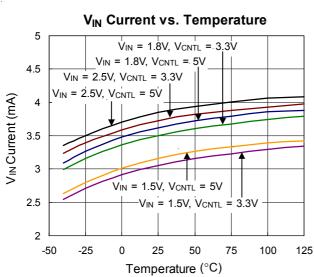
# **Typical Operating Characteristics**

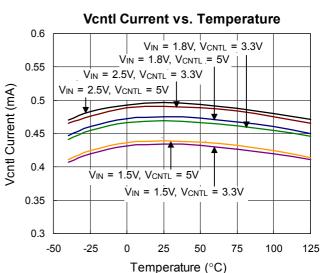




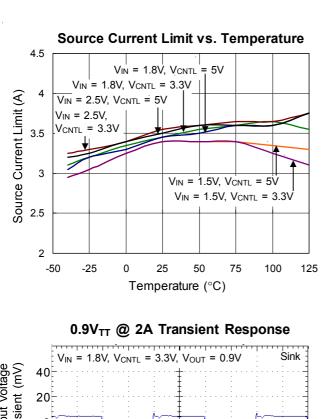


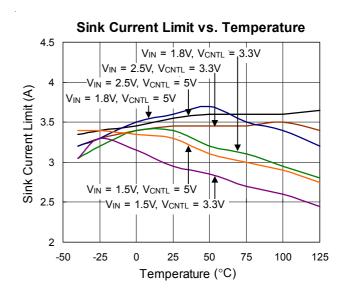


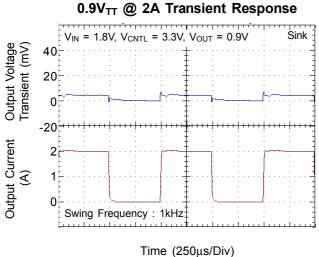


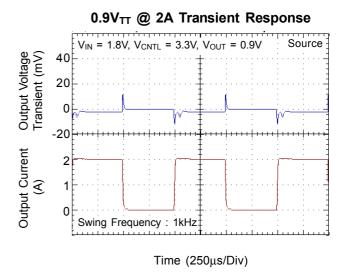


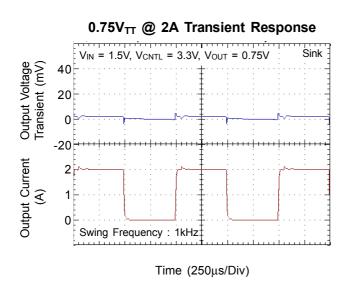


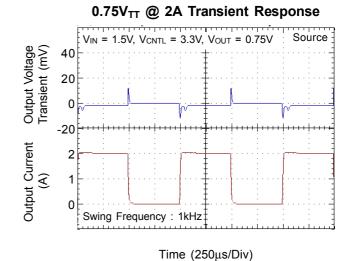








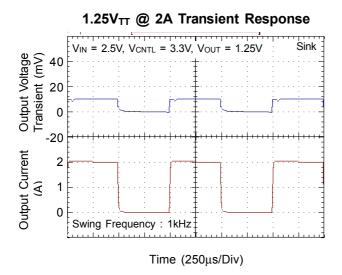


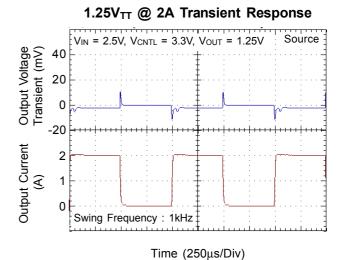


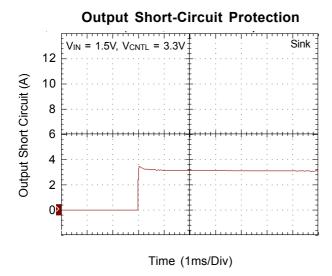
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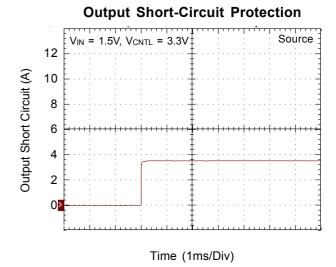
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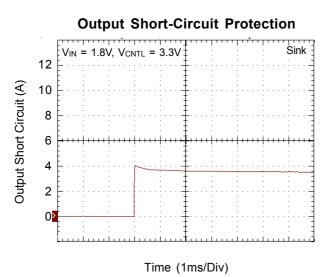


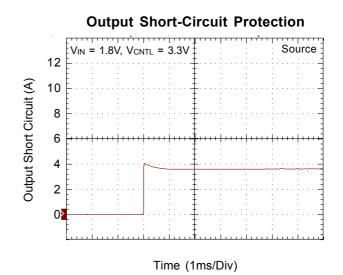


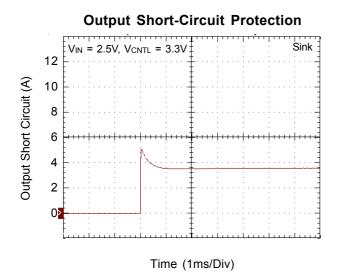


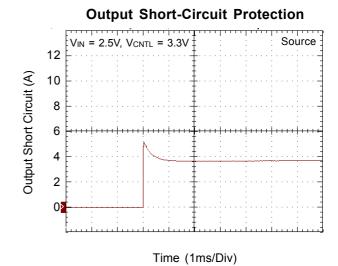














# **Application Information**

# Consideration while designs the resistance of voltage divider

Make sure the sinking current capability of pull-down NMOS if the lower resistance was chosen so that the voltage on  $V_{\mathsf{REFEN}}$  is below 0.2V.

In addition, the capacitor and voltage divider form the lowpass filter. There are two reasons doing this design; one is for output voltage soft-start while another is for noise immunity.

## How to reduce power dissipation on Notebook PC or the dual channel DDR SDRAM application?

In notebook application, using RichTek's Patent "Distributed Bus Terminator Topology" with choosing RichTek's product is encouraged.

Distributed Bus Terminating Topology

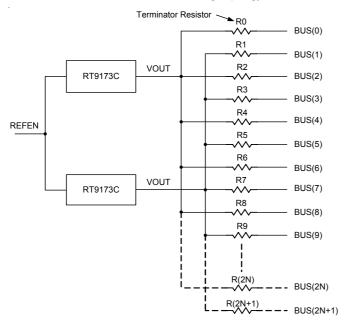
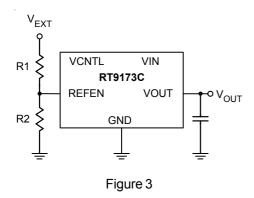


Figure 2



#### **General Regulator**

The RT9173C could also serves as a general linear regulator. The RT9173C accepts an external reference voltage at REFEN pin and provides output voltage regulated to this reference voltage as shown in Figure 3, where

$$V_{OUT} = V_{EXT} \times R2/(R1+R2)$$

As other linear regulator, dropout voltage and thermal issue should be specially considered. Figure 4 and 5 show the  $R_{DS(ON)}$  over temperature of RT9173C in PSOP-8 (Exposed Pad) package. The minimum dropout voltage could be obtained by the product of  $R_{DS(ON)}$  and output current. For thermal consideration, please refer to the relative sections.

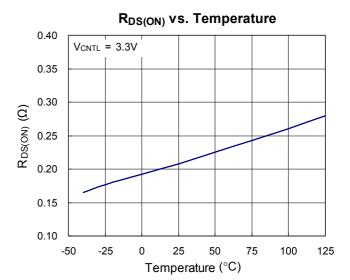
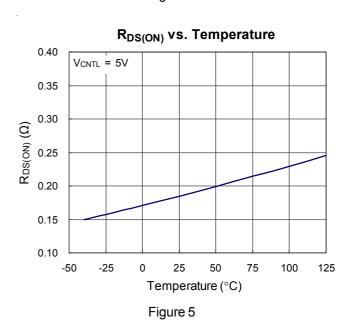


Figure 4



#### Input Capacitor and Layout Consideration

Place the input bypass capacitor as close as possible to the RT9173C. A low ESR capacitor larger than 470uF is recommended for the input capacitor. Use short and wide traces to minimize parasitic resistance and inductance. Inappropriate layout may result in large parasitic inductance and cause undesired oscillation between RT9173C and the preceding power converter.

#### **Thermal Consideration**

RT9173C regulators have internal thermal limiting circuitry designed to protect the device during overload conditions. For continued operation, do not exceed maximum operation junction temperature 125°C. The power dissipation definition in device is:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{Q}$$

The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junction to ambient. The maximum power dissipation can be calculated by following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A)/\theta_{JA}$$

Where  $T_{J(MAX)}$  is the maximum operation junction temperature 125°C,  $T_A$  is the ambient temperature and the  $\theta_{JA}$  is the junction to ambient thermal resistance. The junction to ambient thermal resistance ( $\theta_{JA}$  is layout dependent) for SOP-8 package (Exposed Pad) is 75°C/W on standard JEDEC 51-7 (4 layers, 2S2P) thermal test board. The maximum power dissipation at  $T_A$  = 25°C can be calculated by following formula:

$$P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / 75^{\circ}C/W = 1.33W$$

Figure 6 show the package sectional drawing of SOP-8 (Exposed Pad). Every package has several thermal dissipation paths. As show in Figure 7, the thermal resistance equivalent circuit of SOP-8 (Exposed Pad). The path 2 is the main path due to these materials thermal conductivity. We define the exposed pad is the case point of the path 2.

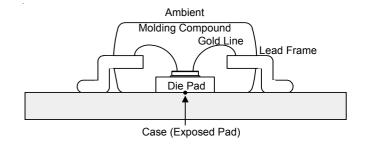


Figure 6. SOP-8 (Exposed Pad) Package Sectional Drawing

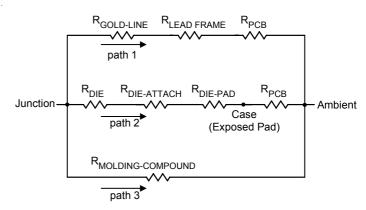


Figure 7. Thermal Resistance Equivalent Circuit

The thermal resistance  $\theta_{JA}$  of SOP-8 (Exposed Pad) is determined by the package design and the PCB design. However, the package design has been decided. If possible, it's useful to increase thermal performance by the PCB design. The thermal resistance can be decreased by adding copper under the expose pad of SOP-8 package.

About PCB layout, the Figure 8 show the relation between thermal resistance  $\theta_{JA}$  and copper area on a standard JEDEC 51-7 (4 layers, 2S2P) thermal test board at  $T_A = 25^{\circ}\text{C.We}$  have to consider the copper couldn't stretch infinitely and avoid the tin overflow. We use the "dog-bone" copper patterns on the top layer as Figure 9.

As shown in Figure 10, the amount of copper area to which the SOP-8 (Exposed Pad) is mounted affects thermal performance. When mounted to the standard SOP-8 (Exposed Pad) pad of 2 oz. copper (Figure 10.a),  $\theta_{JA}$  is 75°C/W. Adding copper area of pad under the SOP-8 (Exposed Pad) (Figure 10.b) reduces the  $\theta_{JA}$  to 64°C/W. Even further, increasing the copper area of pad to 70mm² (Figure 10.e) reduces the  $\theta_{JA}$  to 49°C/W.

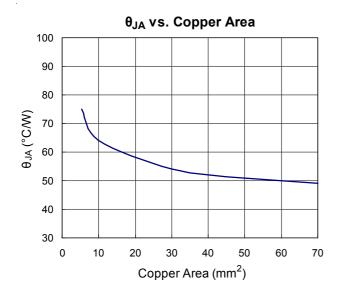


Figure 8

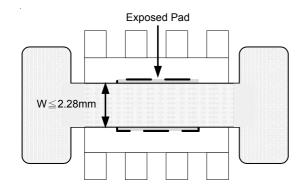


Figure 9.Dog-Bone layout

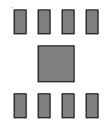


Figure 10 (a). Minimum Footprint,  $\theta_{JA} = 75^{\circ}\text{C/W}$ 

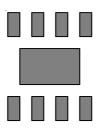


Figure 10 (b). Copper Area =  $10 \text{mm}^2$ ,  $\theta_{JA} = 64 \text{°C/W}$ 

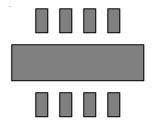


Figure 10 (c). Copper Area =  $30\text{mm}^2$ ,  $\theta_{JA} = 54^{\circ}\text{C/W}$ 

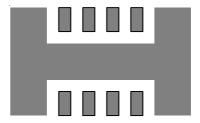


Figure 10 (d). Copper Area =  $50 \text{mm}^2$ ,  $\theta_{JA} = 51 \text{°C/W}$ 

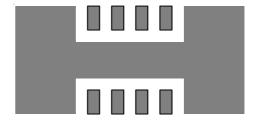
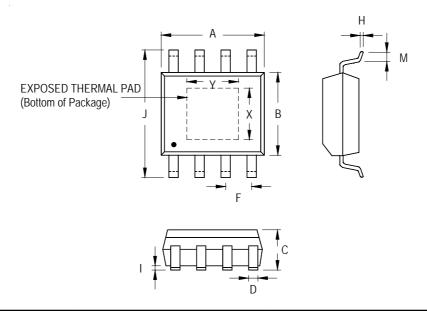


Figure 10 (e). Copper Area =  $70 \text{mm}^2$ ,  $\theta_{JA}$  =  $49^{\circ}\text{C/W}$ 

Figure 10. Thermal Resistance vs. Different Cooper Area Layout Design



## **Outline Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
А	4.801	5.004	0.189	0.197	
В	3.810	3.988	0.150	0.157	
С	1.346	1.753	0.053	0.069	
D	0.330	0.508	0.013	0.020	
F	1.194	1.346	0.047	0.053	
Н	0.191	0.254	0.008	0.010	
I	0.000	0.152	0.000	0.006	
J	5.791	6.198	0.228	0.244	
М	0.406	1.270	0.016	0.050	
Х	2.057	2.515	0.081	0.099	
Υ	2.057	3.404	0.081	0.134	

8-Lead SOP (Exposed Pad) Plastic Package

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